

Laser distillation as a tool to alleviate the effects of dissipation: the subsurface absorption of hydrogen in palladium



Jean Christophe Tremblay

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- **Our humble goals**

- Study the vibrational relaxation of molecules in the vicinity of metallic surfaces
- Perform state resolved dissipative vibrational dynamics of strongly coupled anharmonic systems *fully quantum mechanically*

- **Energy relaxation in dissipative environments**

- Breakdown of the adiabatic Born-Oppenheimer approximation

- **Electron-hole pair coupling at metallic surfaces**

- Chemisorption of gas-phase molecules on thin films produces chemi-current
- Scattering of vibrationally excited molecules on metal leads to emission of electrons
- Reaction rates of chemical processes at surfaces slowed down by electronic friction

Hydrogen at metallic surfaces

- Metals can be used to store hydrogen

- Subsurface and bulk absorption
- Defined potential energy minima in the surface



- Hydrogens in the subsurface are highly reactive

- e.g. alkene hydrogenation on a catalytic surface
- Hydrogen coming out of the subsurface site have the right kinetic energy and direction for an optimally reactive collision
- Hydrogens in the bulk are less reactive, more tightly bound

- Can we populate selectively the subsurface to render a catalyst more active?

A system of interest

● Hydrogen on a Palladium (111) surface

- *Well localized minima above and below the surface*

Ozawa, Arboleda Jr., Roman, Nakanishi, Dino and Kasai *J. Phys.: Condens. Matter* 19, (2007) 365214

- **Present a good catalytic activity**

Kay, Peden and Goodman *Phys. Rev. B* 34 (1986) 817.

- **High quality potential energy surface available**

Ozawa, Roman, Arboleda Jr., Dino, Nakanishi and Kasai *J. Appl. Phys.* 101, (2007) 123530

● How do we propose to manipulate the adsorbate?

- Short and intense shaped laser pulses

● Some key challenges

- Design of efficient and *selective* pulses
- Dissipation of the energy from the adsorbate to the surface

Some perspective

Molecular mechanics

- Classical particles
- Classical force fields

Ab initio molecular dynamics

- Classical EOMs
- Quantum mechanical forces

Hybrid QM/MM methods

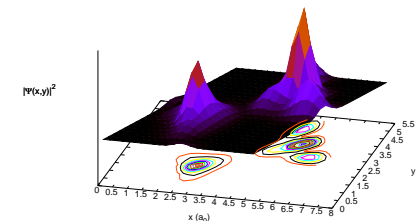
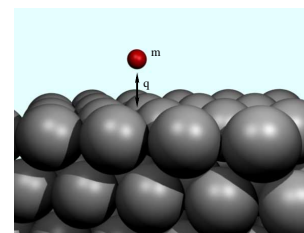
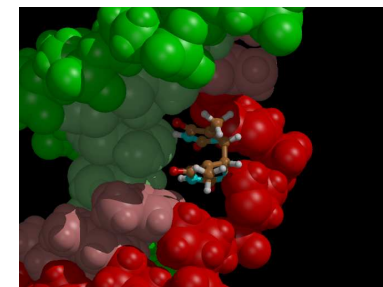
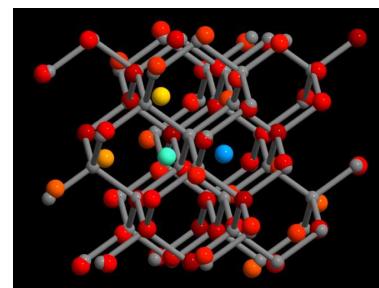
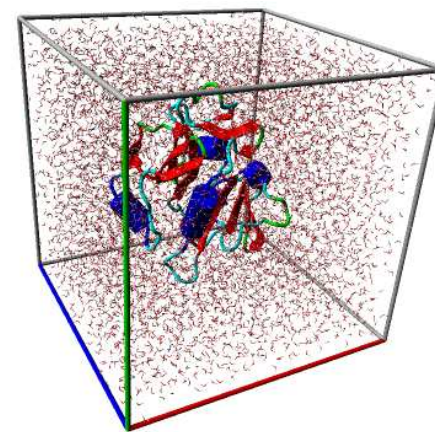
- QM reactive center
- Classical environment

Quantum molecular dynamics

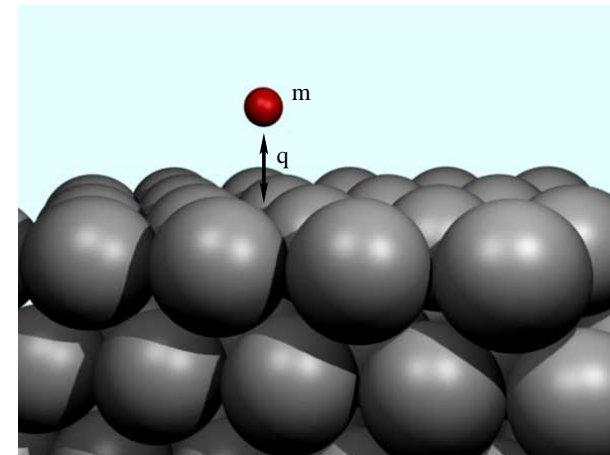
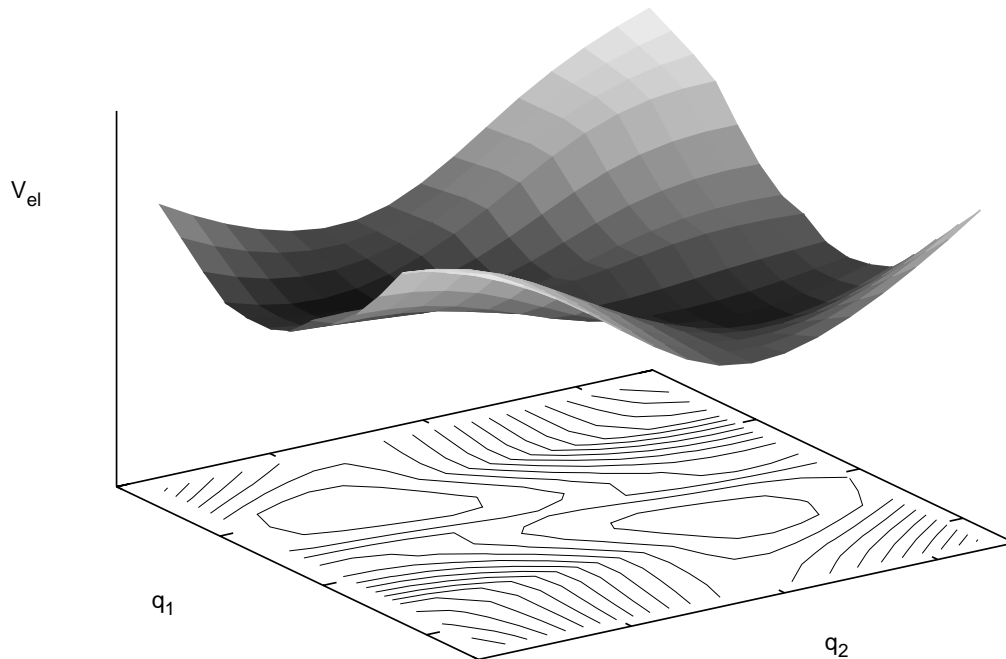
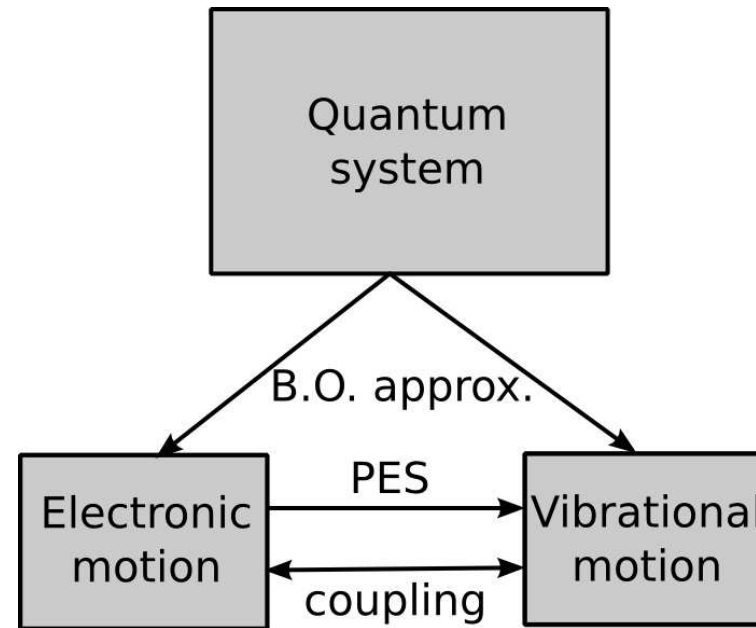
- non-local effects must be taken into account

size

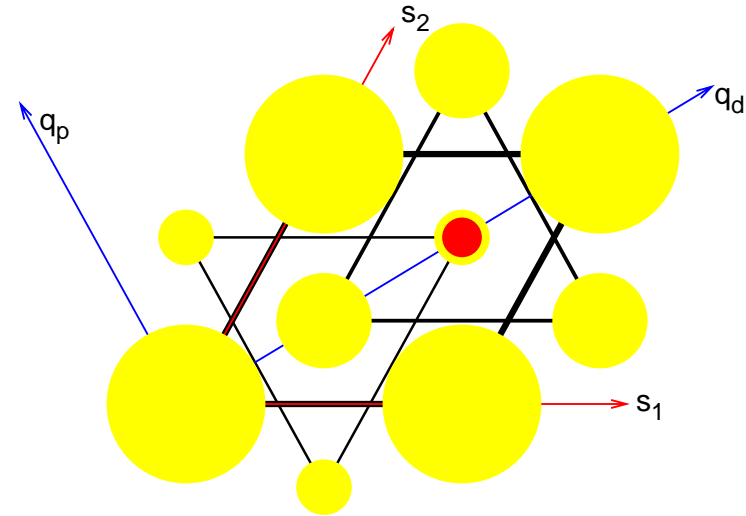
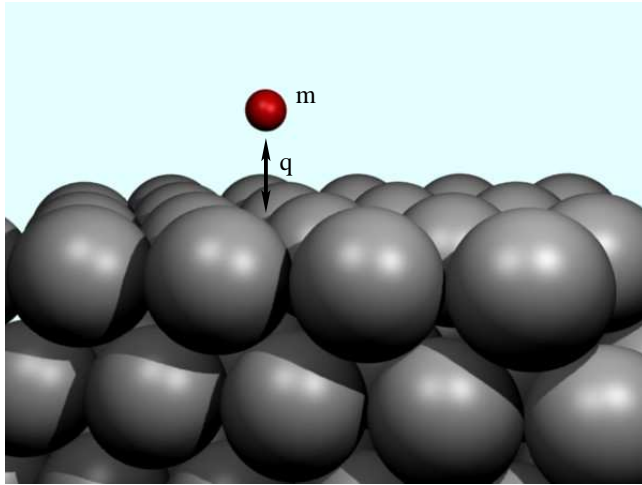
complexity



Born-Oppenheimer approximation



Vibrations of an hydrogen atom on palladium



- **Field-free subsystem Hamiltonian**

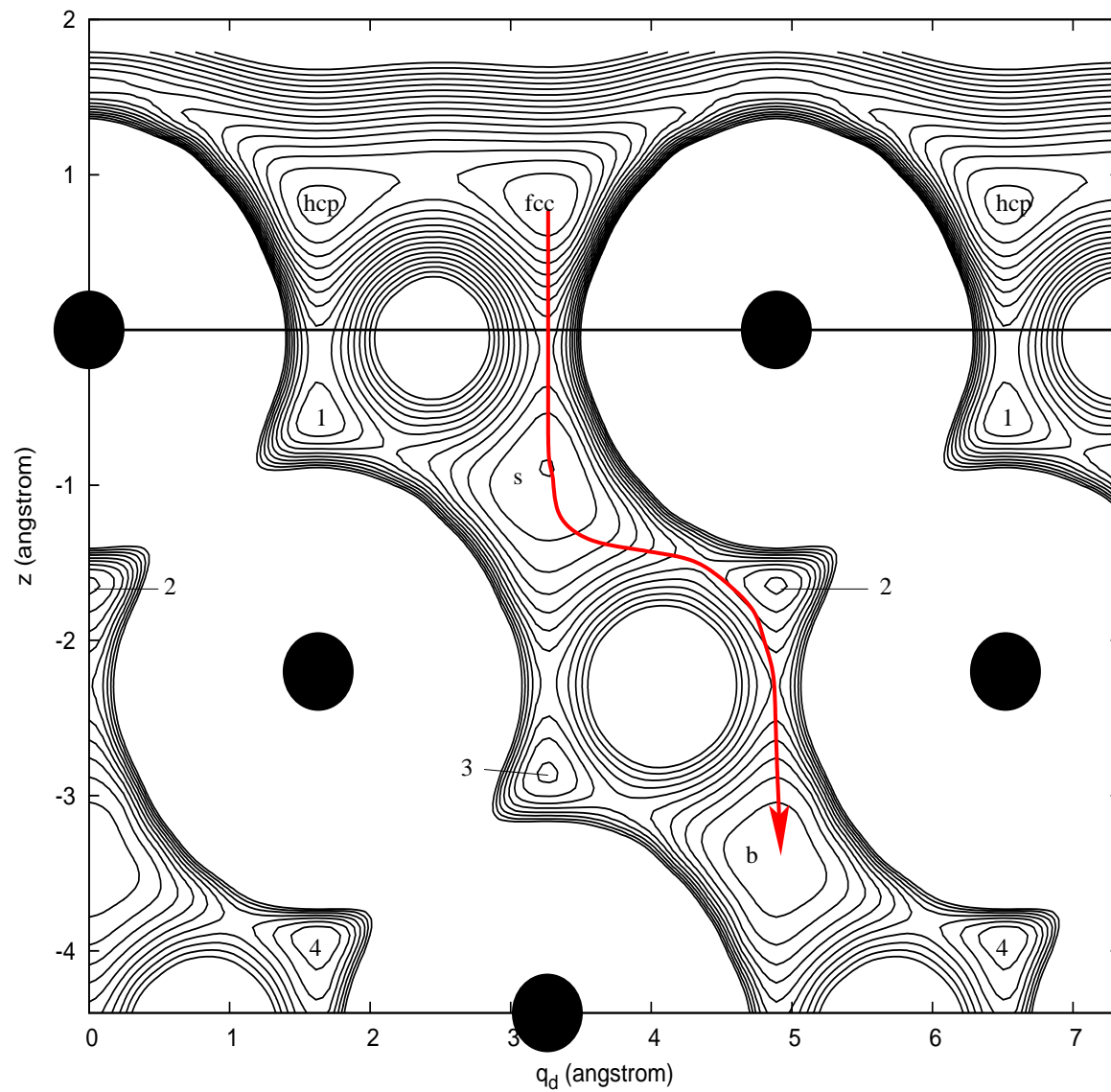
$$\hat{H}_{sub} = -\frac{1}{2m} \left(\frac{1}{\sin^2(\alpha)} \frac{\partial^2}{\partial s_1^2} - \frac{2\cos(\alpha)}{\sin^2(\alpha)} \frac{\partial^2}{\partial s_1 \partial s_2} + \frac{1}{\sin^2(\alpha)} \frac{\partial^2}{\partial s_2^2} + \frac{\partial^2}{\partial z^2} \right) + V(s_1, s_2, z)$$

- **Extract its eigenvalues ϵ_n and eigenvectors $|n\rangle$**

- Multi-dimensional wave functions is a linear combination of simple functions

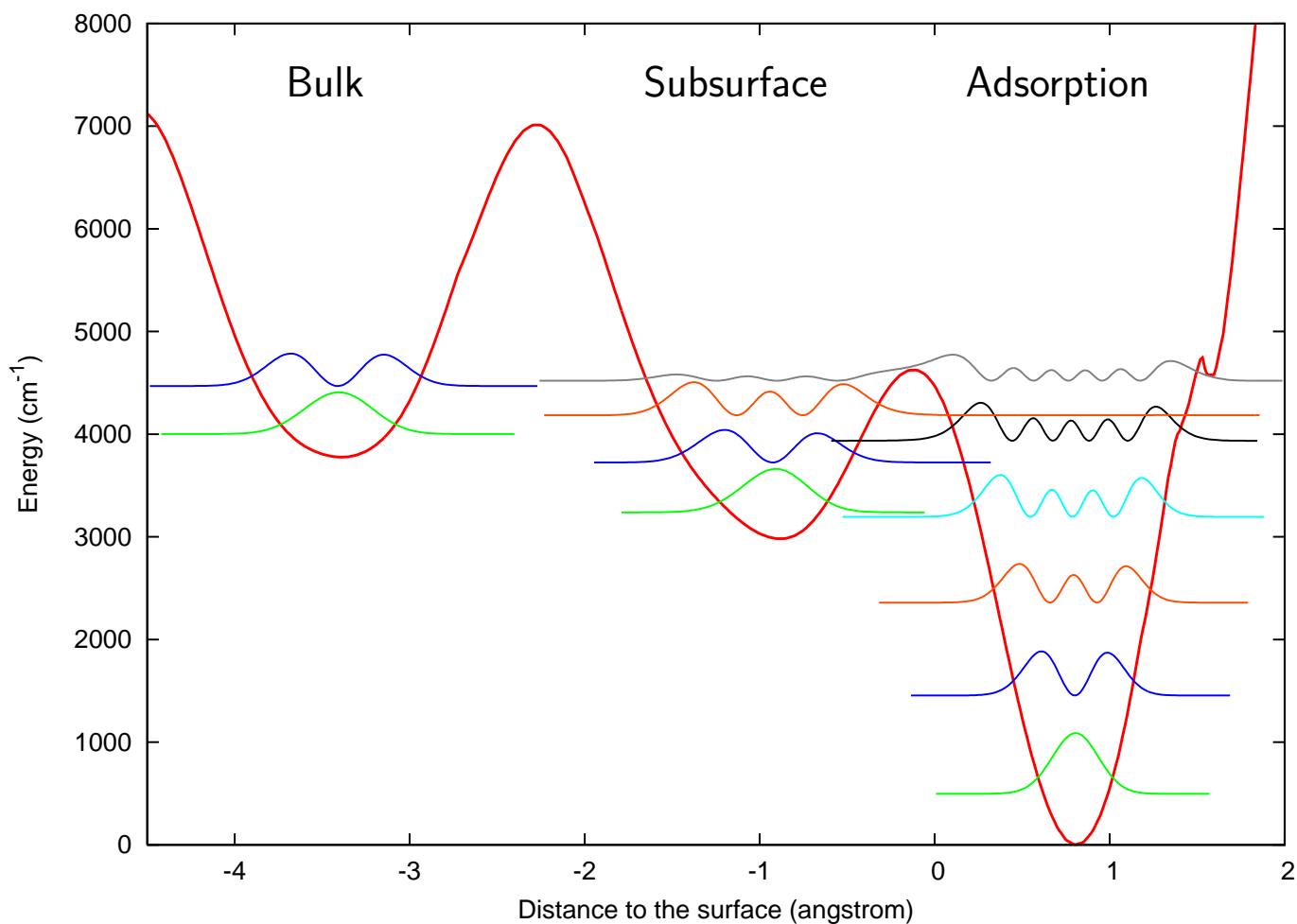
$$|n\rangle = \sum_{ijk} d_{ijk}^n \Phi_i(s_1) \Phi_j(s_2) \Phi_k(z)$$

1D reaction path Hamiltonian



- Resurfacing barrier: 1600 cm^{-1}
- Bulk barrier: 3450 cm^{-1}

The field-free, dissipation-free system eigenstates *in 1D*



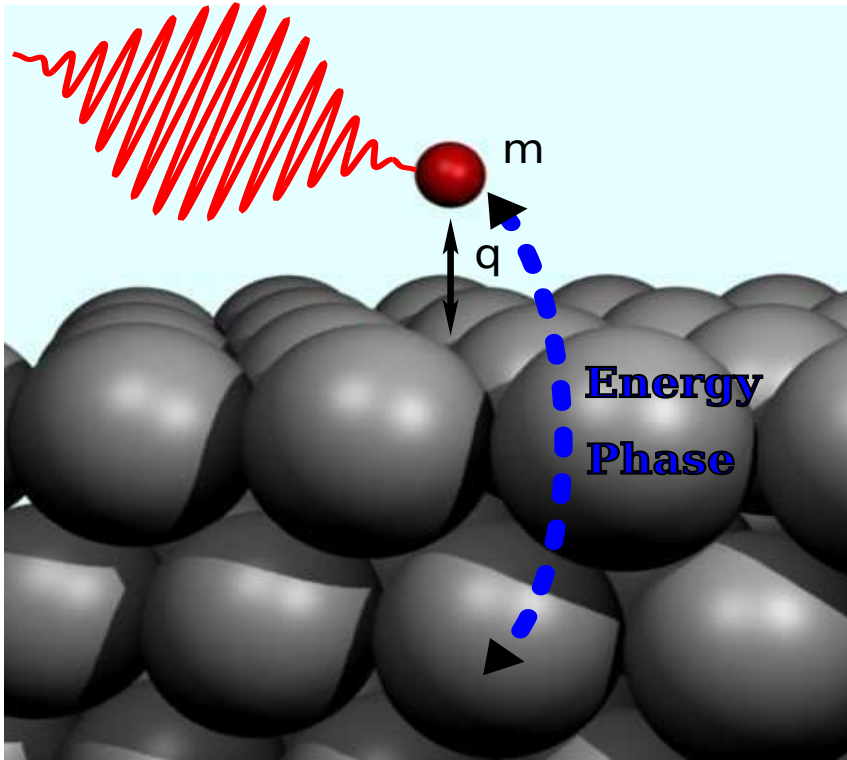
Assignment	Energy (cm ⁻¹)
$gs^{(a)}$	0.0
$\nu_z^{(a)}$	957.6
$2\nu_z^{(a)}$	1861.8
$3\nu_z^{(a)}$	2696.7
$gs^{(s)}$	2741.1
$\nu_z^{(s)}$	3686.5
$4\nu_z^{(a)}$	3438.2
$2\nu_z^{(s)}$	3686.5
$\{3\nu_z^{(s)} - 5\nu_z^{(a)}\}$	4148.6

- 500 sinc-DVR functions on the interval $[-4.5, 2]\text{\AA}$
- Extraction of the lowest lying eigenpairs using the Lanczos algorithm

PART ONE

System-bath dynamics

System-bath dynamics



● Divide and conquer

- System + environment (or bath)
- Their interaction (e.g. electron-hole pair creation, vibration-phonon coupling)
- Neglect interaction of an external electric field with the bath

$$\hat{H}_{tot}(t) = \left(\hat{H}_s + \hat{H}_{ext}(t) \right) + \hat{H}_b + \hat{H}_{sb}$$

- We are only interested in the dynamics of the subsystem
- Solution: Reduced density matrix
 - Environment treated implicitly
 - Effect of the bath → non-unitary evolution of the system

Reduced density matrix for open systems

- Total hamiltonian for a given system

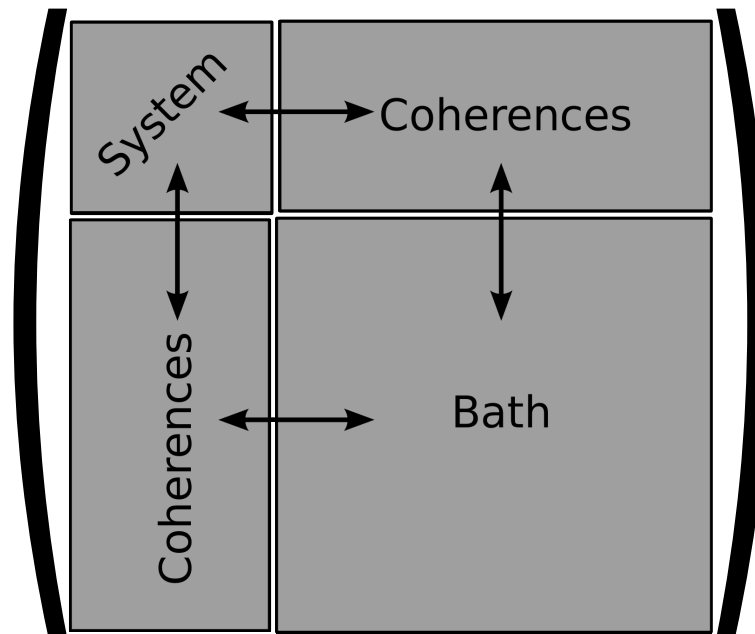
$$\hat{H}_{tot} = \hat{H}_s + \hat{H}_b + \hat{H}_{sb}$$

- Admits stationnary solutions

$$\hat{H}_{tot}|\psi\rangle = E|\psi\rangle$$

- Density matrix

$$\hat{\chi} = |\psi\rangle\langle\psi| =$$



Reduced density matrix for open systems

- Total hamiltonian for a given system

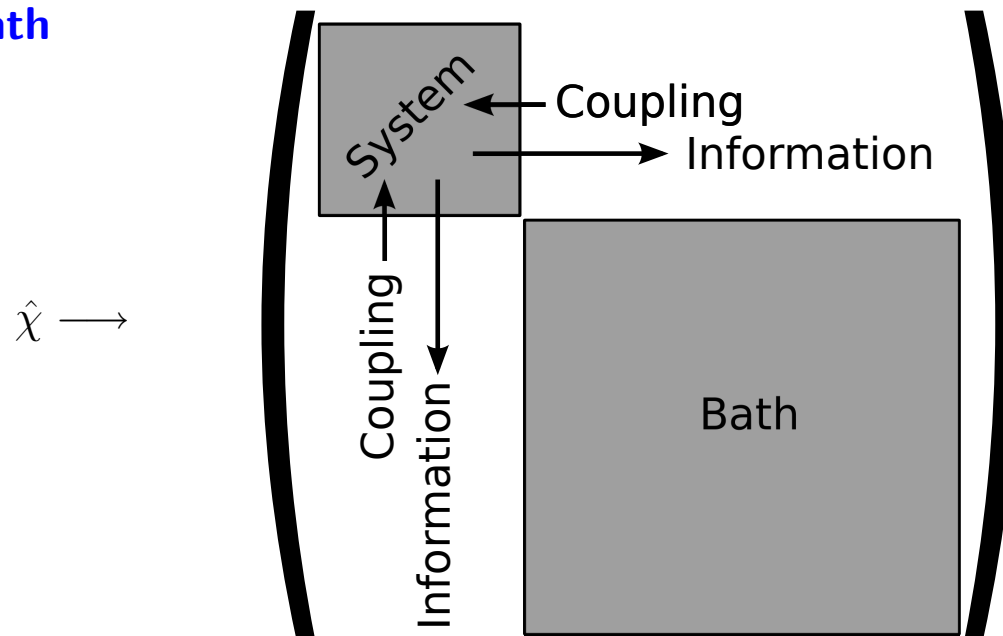
$$\hat{H}_{tot} = \hat{H}_s + \hat{H}_b + \hat{H}_{sb}$$

- Admits stationnary solutions

$$\hat{H}_{tot}|\psi\rangle = E|\psi\rangle$$

- Reduced Density Matrix

— Trace out the bath



Reduced density matrix formalism

- System evolution characterized by the Liouville-von Neumann equation

$$\frac{\partial \hat{\rho}(t)}{\partial t} = -\frac{i}{\hbar} [\hat{H}(t), \hat{\rho}(t)] + \mathcal{L}_D \hat{\rho}(t)$$

$\hat{H}(t) = \hat{H}_s - \hat{\mu}F(t)$ and \mathcal{L}_D is the dissipative Liouvillian

- Use the subsystem eigenstates to represent RDM

$$\hat{\rho}(t) = \sum_{mn} \rho_{mn}(t) |m\rangle \langle n|$$

- EOM are simple in the basis of eigenvectors of the subsystem

$$\frac{d\rho_{mn}(t)}{dt} = -\frac{i}{\hbar} \omega_{mn} \rho_{mn}(t) + \frac{iF(t)}{\hbar} \sum_i (\mu_{mi} \rho_{in}(t) - \rho_{mi}(t) \mu_{in}) + \langle \langle m | \mathcal{L}_D \hat{\rho} | n \rangle \rangle$$

where $\omega_{mn} = (\epsilon_m - \epsilon_n)$, and $\langle \langle m | \mathcal{L}_D \hat{\rho} | n \rangle \rangle$ represents the dissipation

Semi-group treatment of dissipation

• Lindblad semi-group formalism

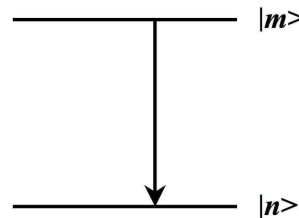
- Ensures semi-positivity of $\hat{\rho}(t)$
- Probabilistic interpretation of $\rho_{nn}(t)$

$$\mathcal{L}_D \hat{\rho}(t) = -\frac{1}{2} \sum_k \left([\hat{C}_k \hat{\rho}(t), \hat{C}_k^\dagger] + [\hat{C}_k, \hat{\rho}(t) \hat{C}_k^\dagger] \right)$$

• Energy relaxation

- Raising/lowering operators

$$\hat{C}_k \rightarrow \sqrt{\Gamma_{m \rightarrow n}} |n\rangle \langle m|$$



• Phase relaxation

- Scaled Hamiltonian

$$\hat{C}_k \rightarrow \sqrt{\gamma^*} \hat{H}_s$$

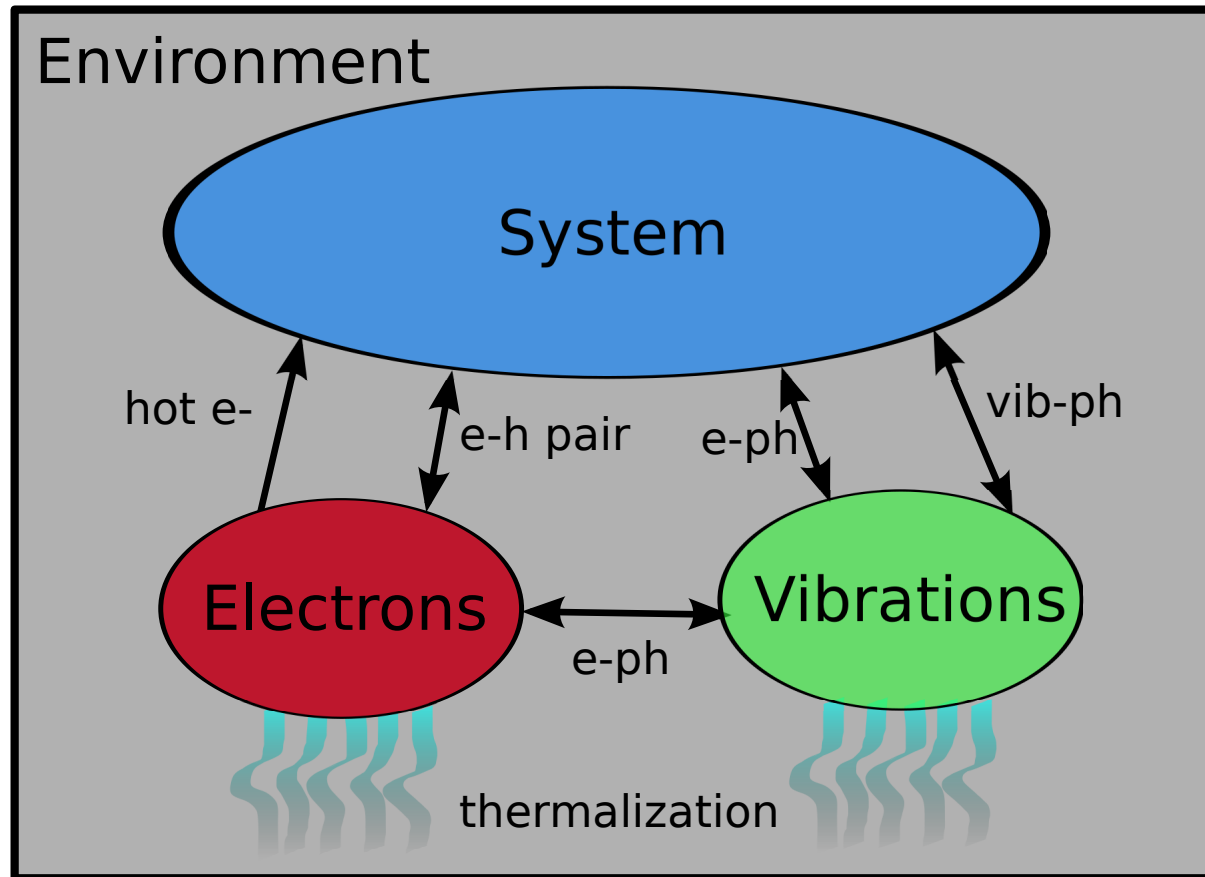
We set $\gamma^* = \Gamma_{1 \rightarrow 0}$

- Need the transition rates $\Gamma_{m \rightarrow n} \longrightarrow$ problem-specific

PART TWO

**Nonadiabatic effects
via electronic friction**

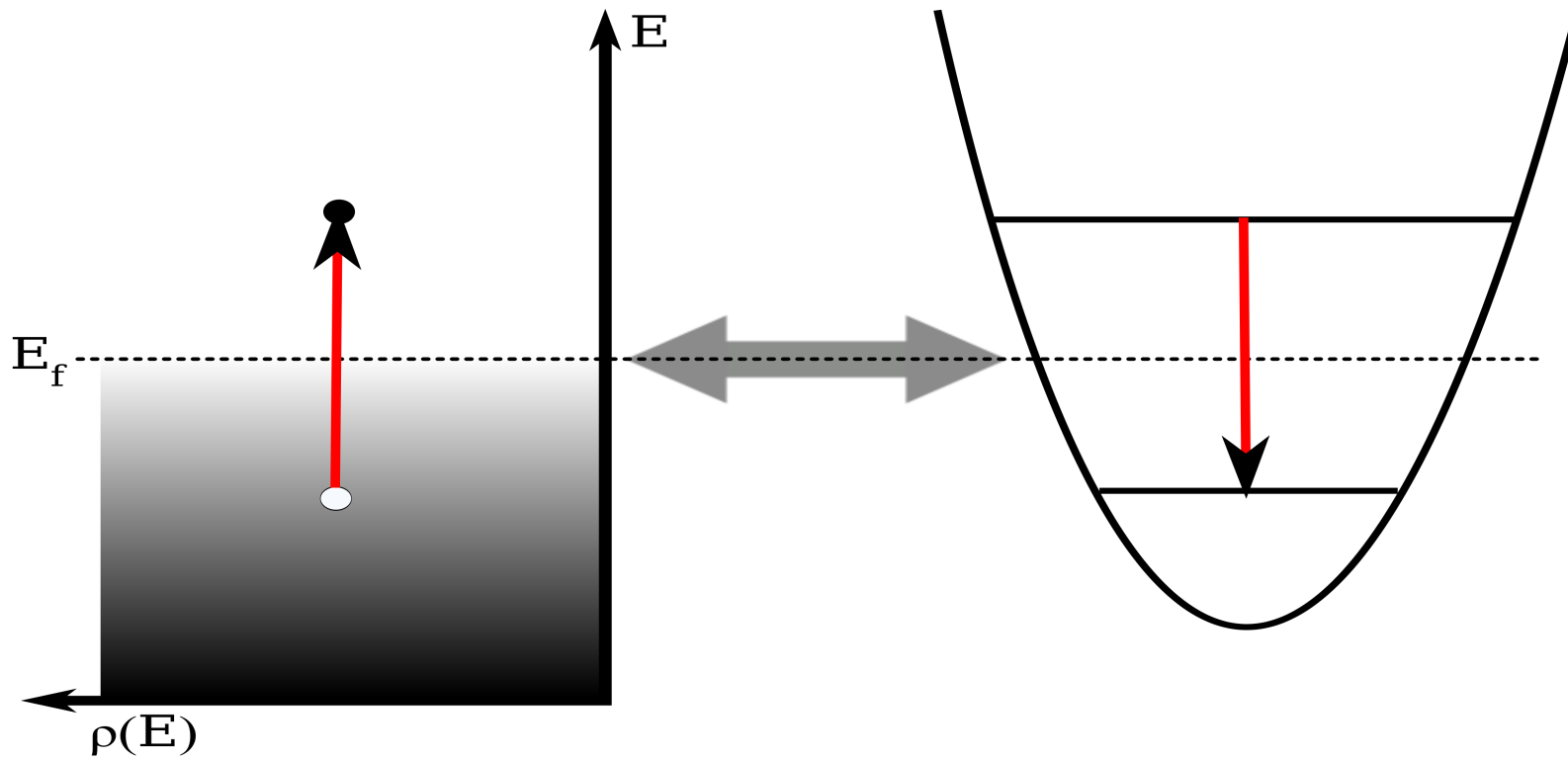
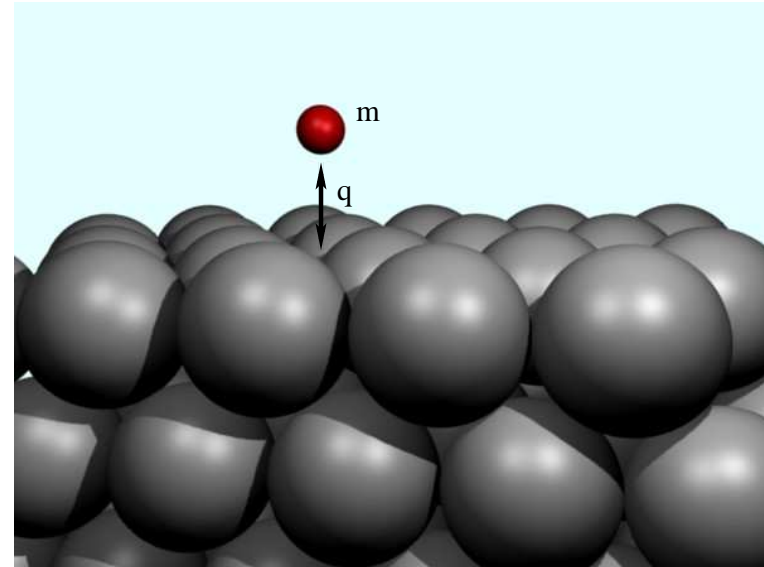
Types of couplings



- Non-adiabatic coupling → dominates for metallic environments
- Vibration-phonon coupling → dominates for semiconductors and bio-molecules
- Hot e^- → mediates indirect excitation via environment

Nonadiabatic coupling of an adsorbate to a surface

- **Vibrational damping**



Position-dependent anharmonic electron-hole pair coupling model

- Fermi's Golden rule

$$\Gamma_{m \rightarrow n} = \frac{2\pi}{\hbar} \sum_f |\langle f | \hat{W} | i \rangle|^2 \delta(E_i - E_f)$$

- Nonadiabatic coupling operator

$$\hat{W} = \sum_{j=1}^N \frac{-\hbar^2}{2m_j} \left(\frac{\partial^2}{\partial x_j^2} + \frac{\partial^2}{\partial y_j^2} + \frac{\partial^2}{\partial z_j^2} \right)$$

– Factorize vibrational ($|n\rangle, |m\rangle$) and electronic parts ($|e_i\rangle, |e_f\rangle$) of WF

- Separate treatment for each mode q

$$\Gamma_{m \rightarrow n} = \gamma^{(q)} |\langle m | \rho_{embed}(x, y, z) \frac{\partial}{\partial q} | n \rangle|^2$$

where $\rho_{embed}(x, y, z)$ is the density of an atom embedded in a FEG
and $\gamma^{(q)}$ is the mode scaling constant

Embedding density models

1. Jellium model (or free lunch model)

$$\rho_{embd}(\vec{R}) = \rho_0 e^{-2\sqrt{2I}z}$$

where I is the metal work function and ρ_0 is the free metal density

2. Free metal density model

$$\rho_{embd}(\vec{R}) = \rho_{metal}(\vec{R})$$

- Requires a single periodic DFT calculation to generate the embedding density profile

3. Perturbed metal density model

$$\rho_{embd}(\vec{R}) = \rho_{calc}(\vec{R}) - \rho_\infty$$

- Requires many periodic DFT calculations to generate the embedding density profile
- Scaling chosen to fit the Persson lifetime at the equilibrium geometry

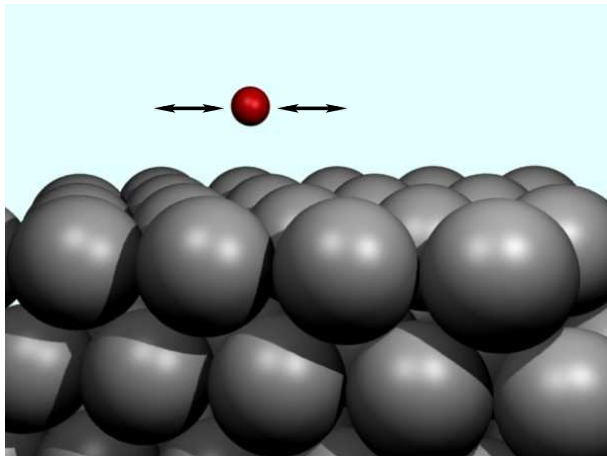
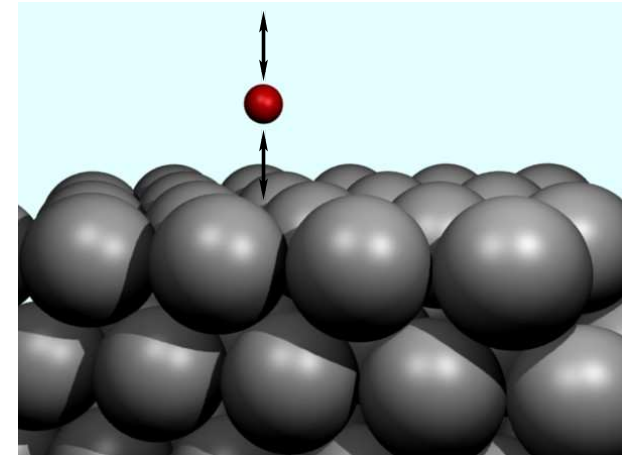
Lifetimes at different sites

Perpendicular mode

Model	fcc site / fs	hcp site / fs	Subsurface / fs	Bulk / fs
jellium	1348.7 fs	2512.7	389.0	366.9
metal	369.9	1190.8	373.2	349.8
perturbed	392.4	1269.6	525.5	450.8

$$\tau_z^{(f)} = 1/\Gamma_{persson}^{(f)} \simeq 393 \text{ fs}$$

$$\tau_z^{(s)} = 1/\Gamma_{persson}^{(s)} \simeq 417 \text{ fs}$$



Parallel mode

Model	fcc site / fs	hcp site / fs	Subsurface / fs	Bulk / fs
jellium	1130.4	1366.4	289.2	290.6
metal	326.5	395.4	278.9	277.4
perturbed	349.8	427.5	391.2	361.9

PART THREE

**Design of control
laser fields**

Excitation mechanism

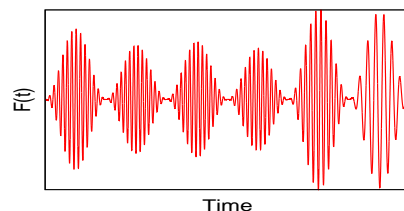
- How do we want to steer the reaction in a controlled manner?
 - Interaction with short, intense laser field

$$\hat{H}_{ext}(t) = -\vec{\mu}(\vec{R}) \cdot \vec{F}(\vec{R}, t) \sim -\vec{\mu}(\vec{R}) \cdot \vec{F}(t)$$

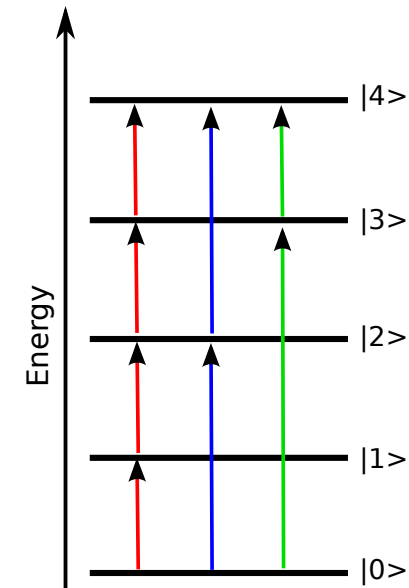
- Rational pulses design

- Series of π -pulses

$$F_{ref}(t) = \sum_k F_{kz} U_k(t) \cos(\omega_k t) ; \quad F_{kz} = \frac{2\pi\hbar}{t_p |\mu_k|} ;$$
$$U_k(t) = \begin{cases} \sin^2\left(\frac{\pi(t-t_k)}{t_p}\right) & \text{for } t_k < t < t_k + t_p \\ 0 & \text{otherwise} \end{cases}$$



- Reaction paths



Excitation using guided locally optimal control theory

- Define a cost functional

$$J[F(t)] = \langle\langle \hat{G}(t_f) | \rho(t_f) \rangle\rangle - \int_0^{t_f} \frac{|F(t) - F_{ref}(t)|^2}{\hbar\alpha(t)} dt$$

- Rewrite as a time-dependent function

$$J[F(t)] = \int_0^{t_f} \frac{d}{dt} \left(\langle\langle \hat{G}(t) | \rho(t) \rangle\rangle \right) dt - \int_0^{t_f} \frac{|F(t) - F_{ref}(t)|^2}{\hbar\alpha(t)} dt + \langle\langle \hat{G}(0) | \rho(0) \rangle\rangle$$

- Following a conventional variational procedure, we obtain

$$F(t) = F_{ref}(t) - \hbar\alpha(t) \langle\langle \hat{G}(t) \hat{\mu} | \mathbf{Im}[\rho(t)] \rangle\rangle$$

- A natural choice for the guiding function $\hat{G}(t)$

$$G(t) = \sum_{k=1}^L g_k(t) P_k$$

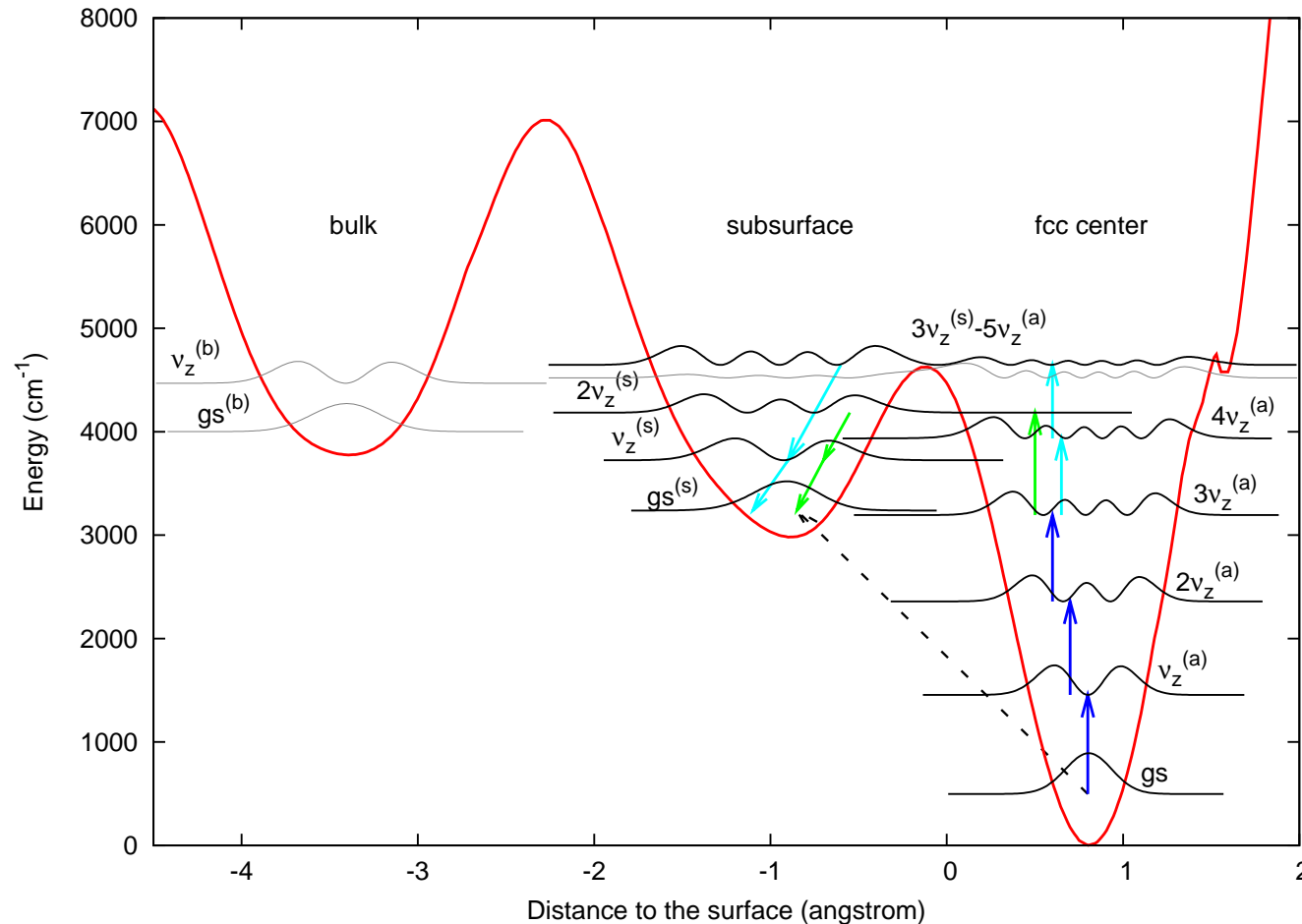
PART FOUR

Laser control of vibrational dynamics

Proposed excitation mechanism *in 1D*

- Direct excitation not possible

- Populate some intermediate state
- Use energy relaxation as a dump mechanism



$$\tau_{m \rightarrow n} \sim \frac{1}{\Gamma_{m \rightarrow n}}$$

$$\tau_{1 \rightarrow 0}^{(a)} = 867\text{fs}$$

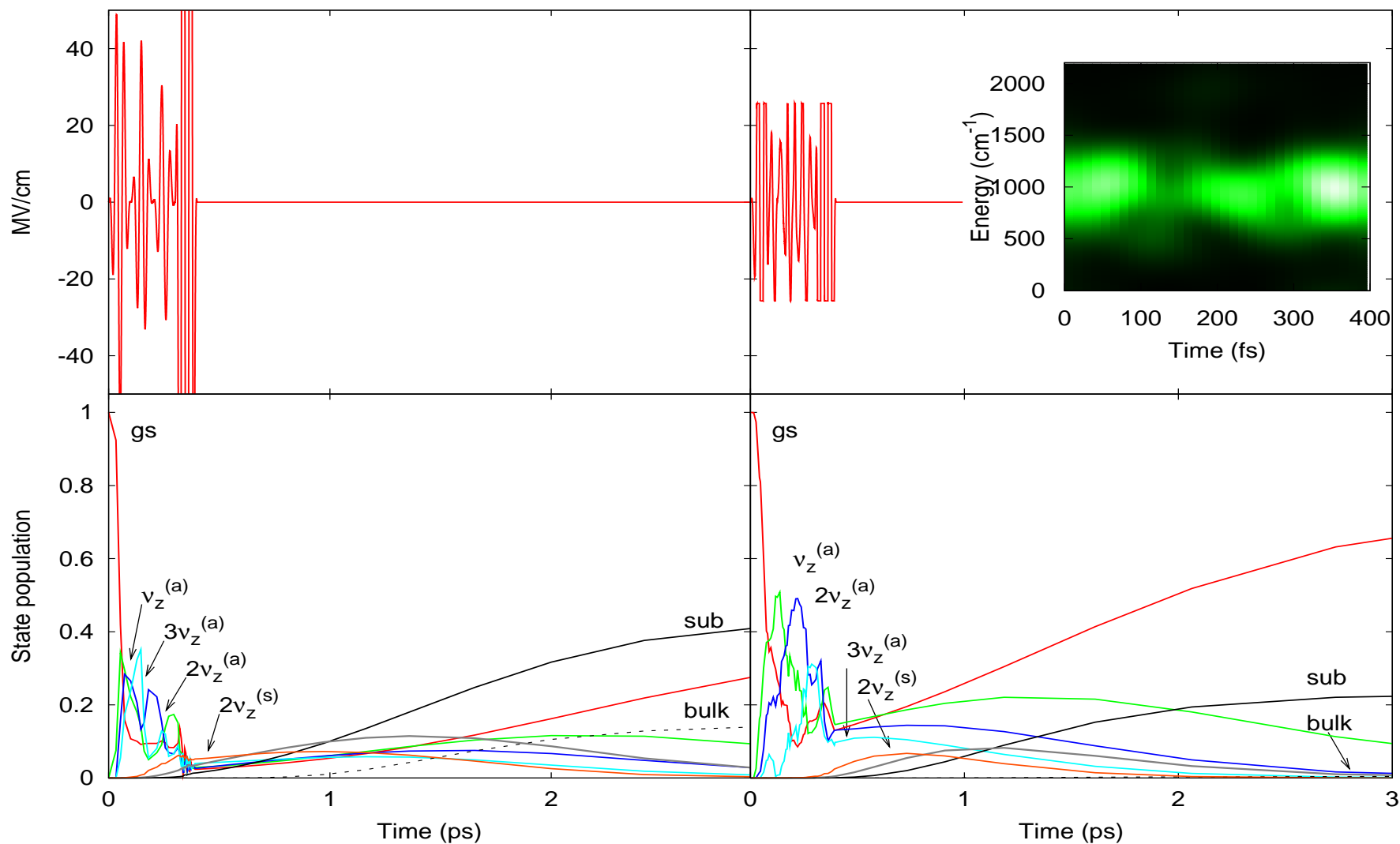
$$\tau_{2 \rightarrow 1}^{(a)} = 446\text{fs}$$

$$\tau_{3 \rightarrow 2}^{(a)} = 313\text{fs}$$

$$\tau_{1 \rightarrow 0}^{(s)} = 497\text{fs}$$

$$\tau_{2 \rightarrow 1}^{(s)} = 265\text{fs}$$

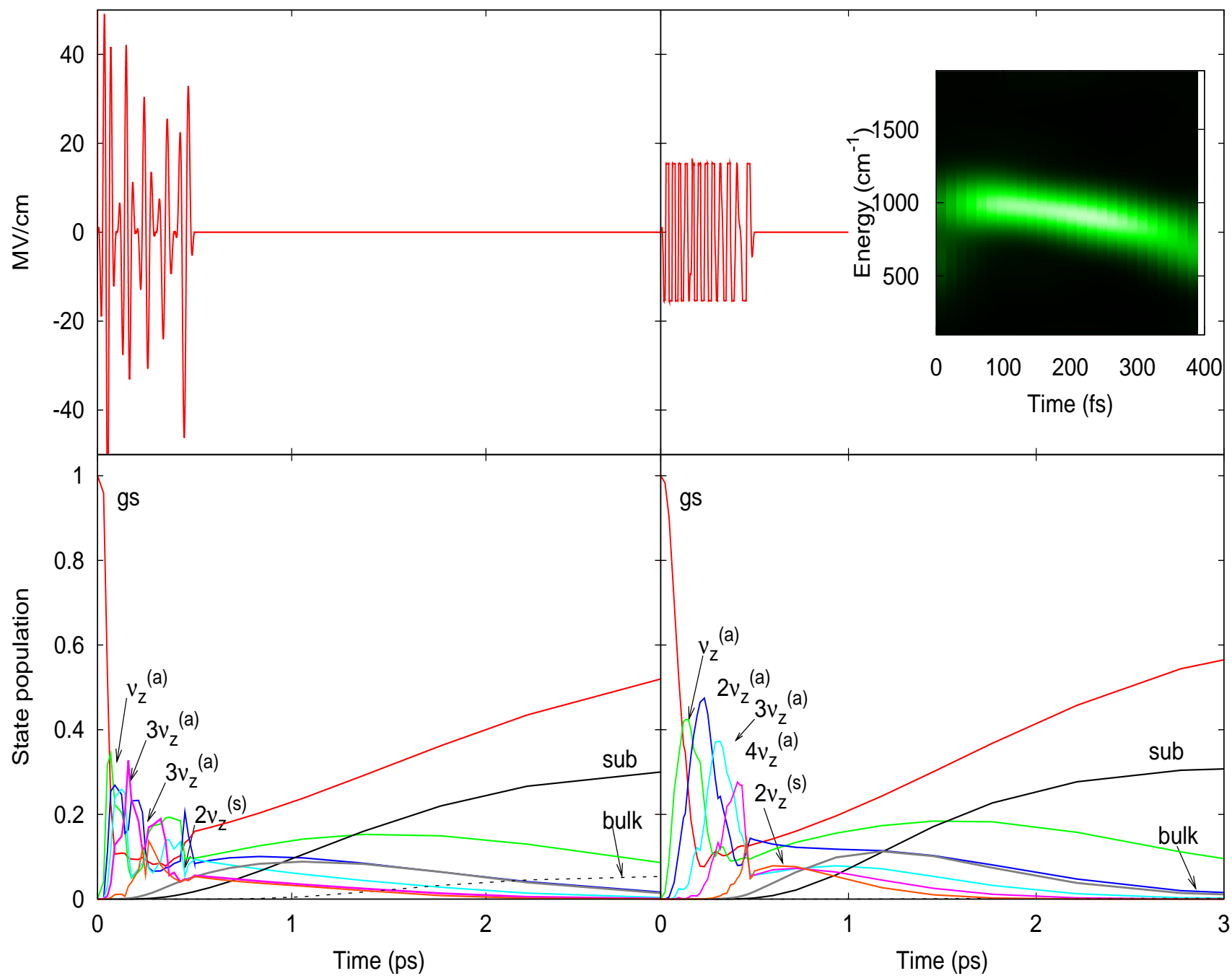
Excitation along reaction path 1



Series of non-overlapping π -pulses

$$F(t) = \sum_k F_{0k} \sin^2 \left(\frac{\pi(t - t_k)}{\Delta t_k} \right) \cos(\omega_k t) ; F_{0k} = \frac{2\pi\hbar}{\Delta t_k |\mu_k|}$$

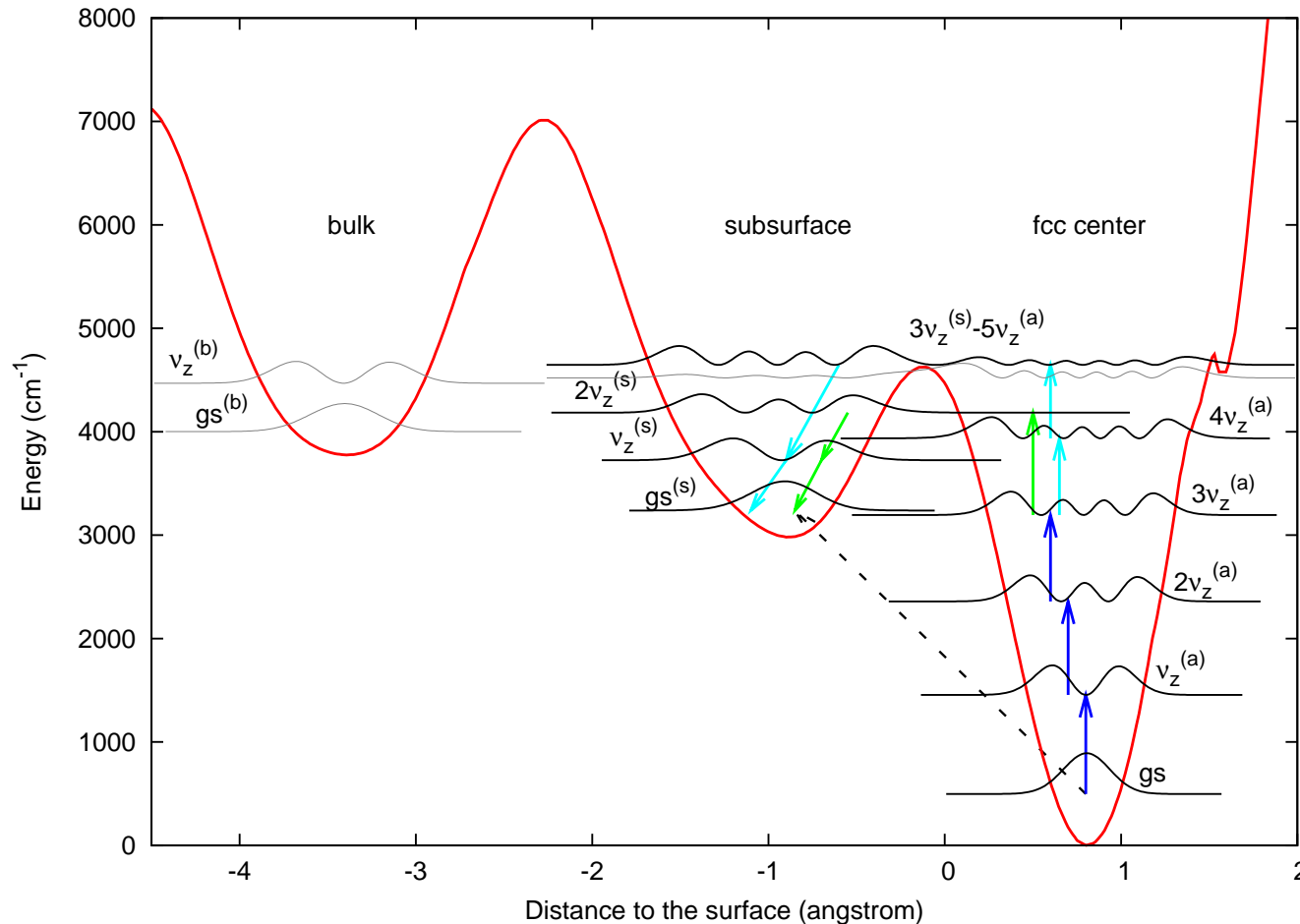
Excitation along reaction path 2



Proposed excitation mechanism *in 1D*

- Direct excitation not possible

- Populate some intermediate state
- Use energy relaxation as a dump mechanism



$$\tau_{m \rightarrow n} \sim \frac{1}{\Gamma_{m \rightarrow n}}$$

$$\tau_{1 \rightarrow 0}^{(a)} = 867\text{fs}$$

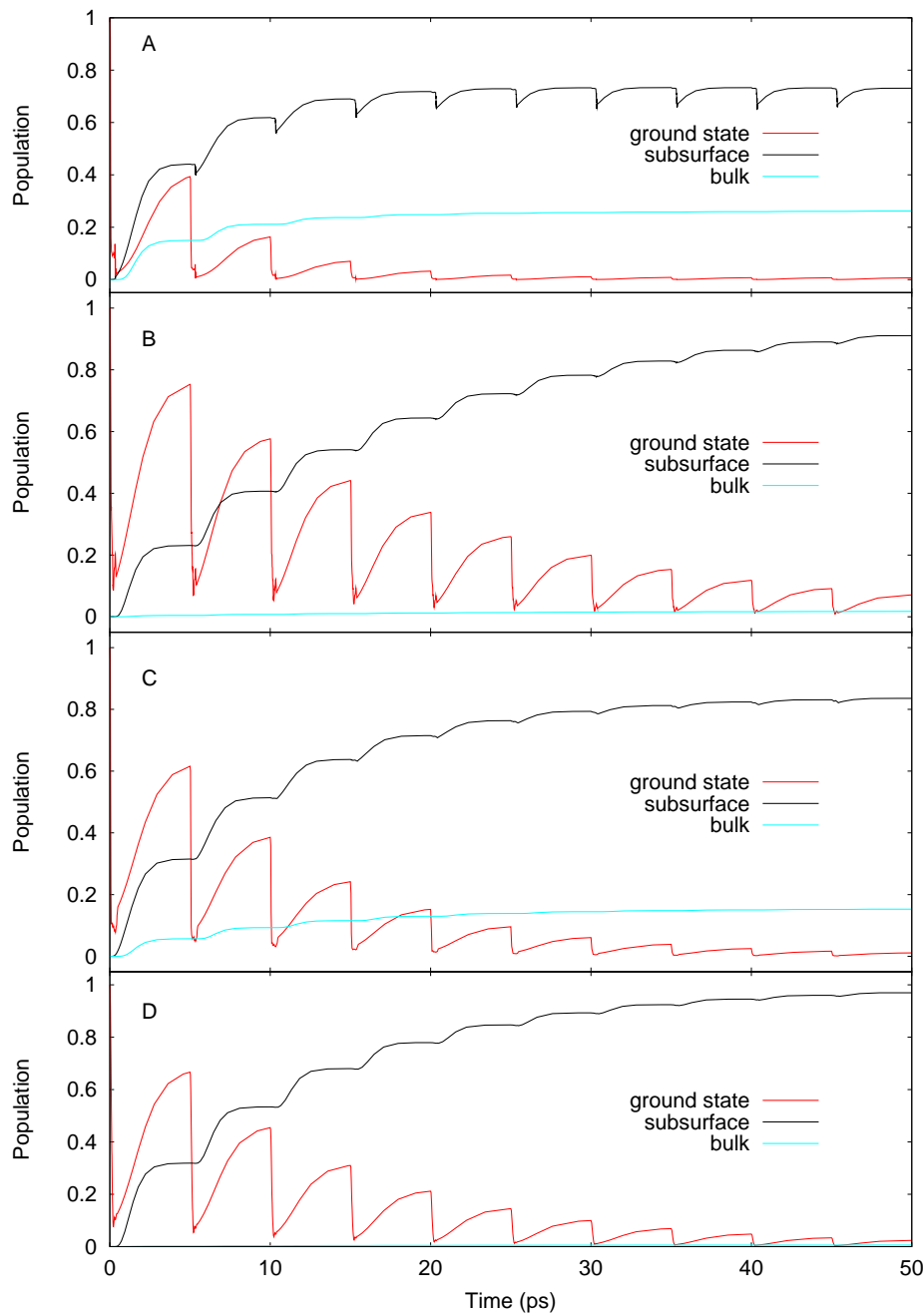
$$\tau_{2 \rightarrow 1}^{(a)} = 446\text{fs}$$

$$\tau_{3 \rightarrow 2}^{(a)} = 313\text{fs}$$

$$\tau_{1 \rightarrow 0}^{(s)} = 497\text{fs}$$

$$\tau_{2 \rightarrow 1}^{(s)} = 265\text{fs}$$

Selective Subsurface Absorption by Laser Distillation (SSALaD)

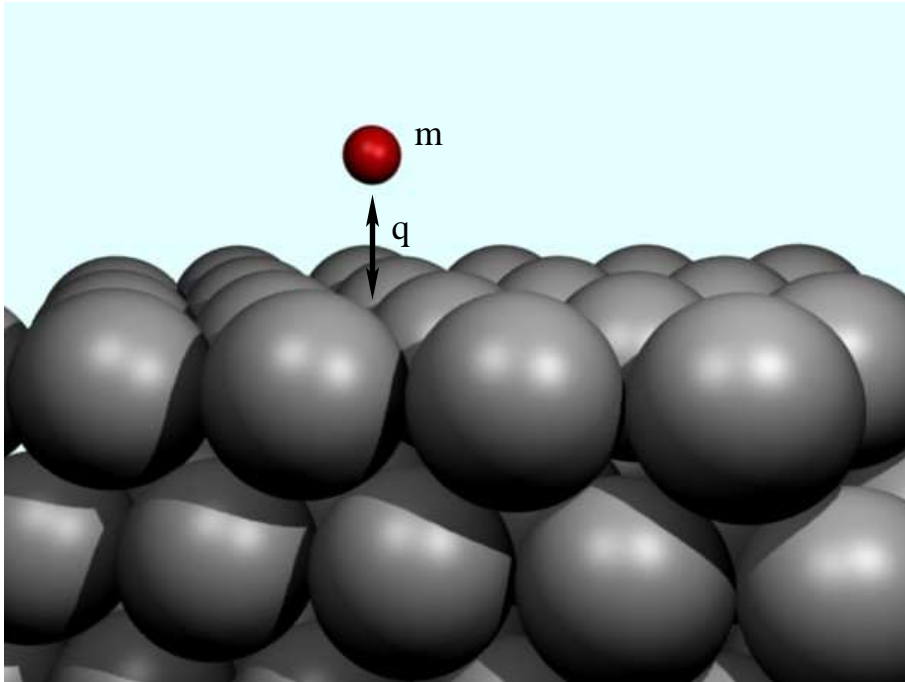


Transfer efficiency

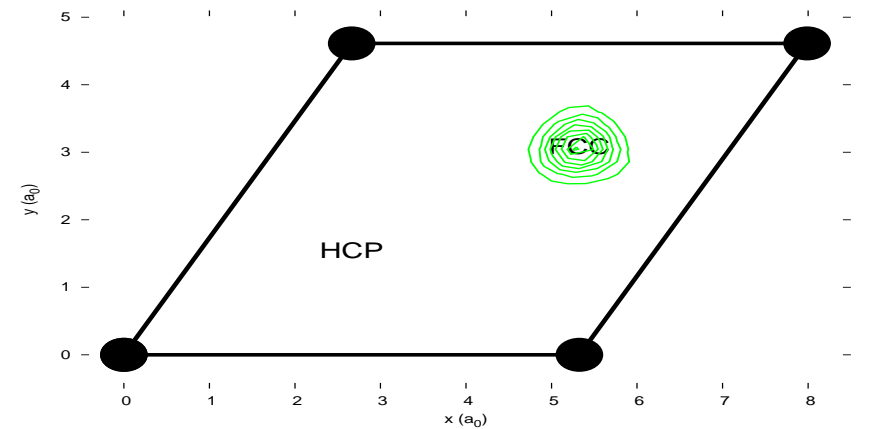
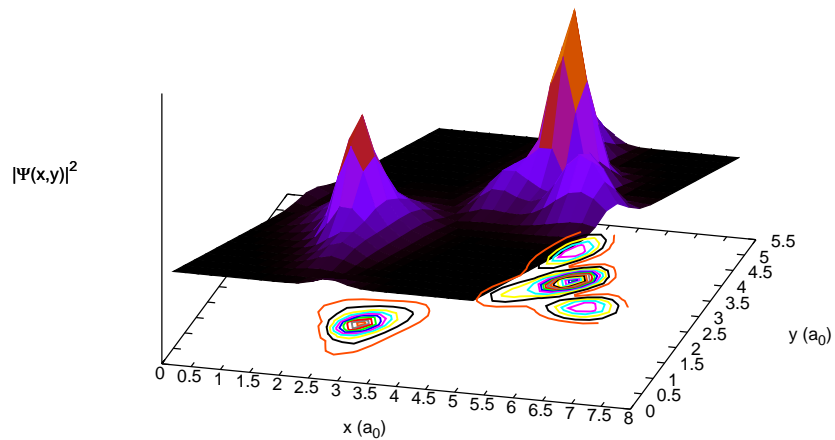
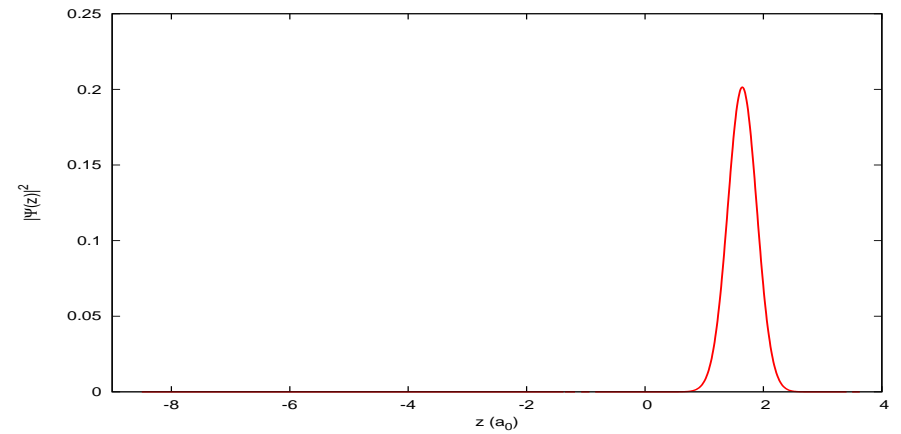
$$P(t) = P_0 (1 - e^{-Rt})$$

Simulation	P_0 (%)	R (ps ⁻¹)
RP1, rational	71.8	0.198
RP1, optimized	97.7	0.054
RP2, rational	84.1	0.095
RP2, optimized	99.0	0.077

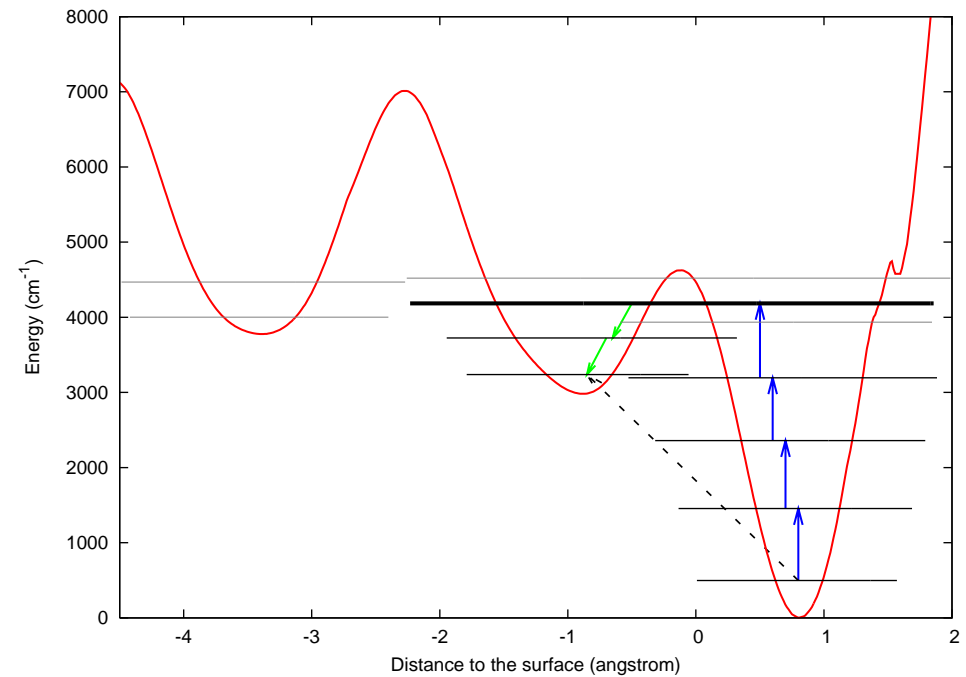
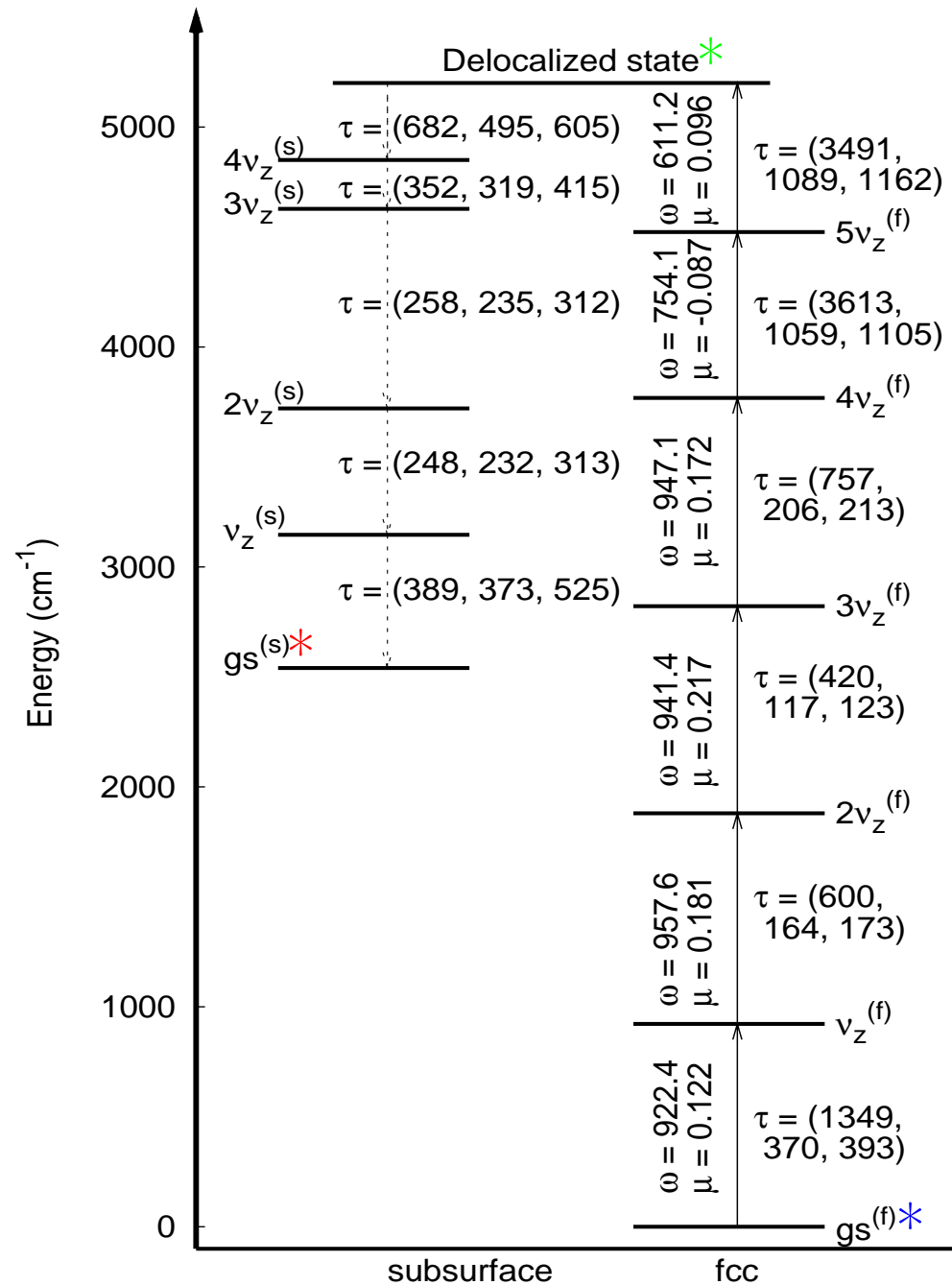
Three-dimensional wave-function



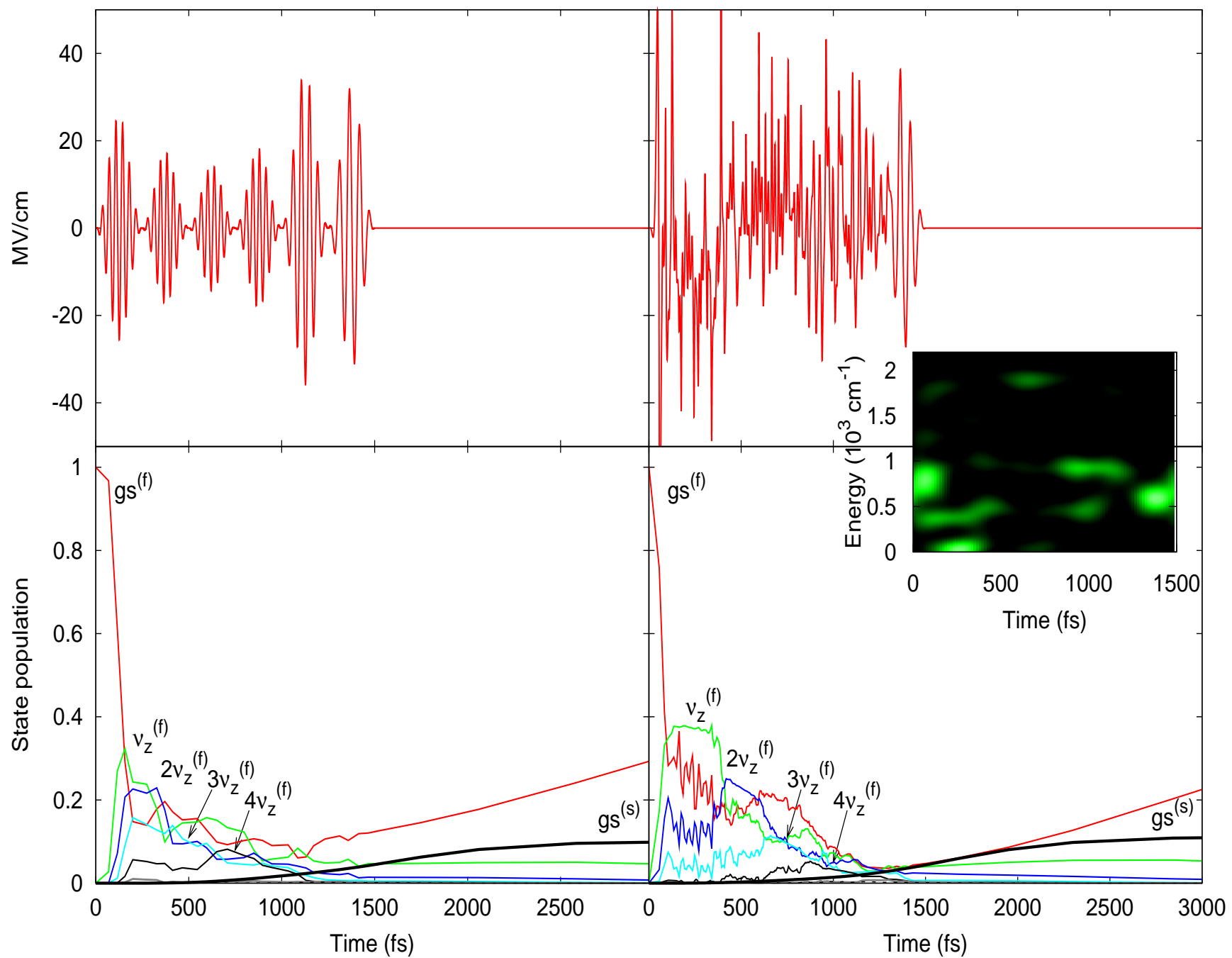
Assignment	Energy (cm^{-1})
$g_s^{(f)}$	0.0
$g_s^{(h)}$	288.3
$g_s^{(s)}$	2540.5
$\nu_{qp}^{(f)}$	717.4
$\nu_z^{(f)}$	922.4



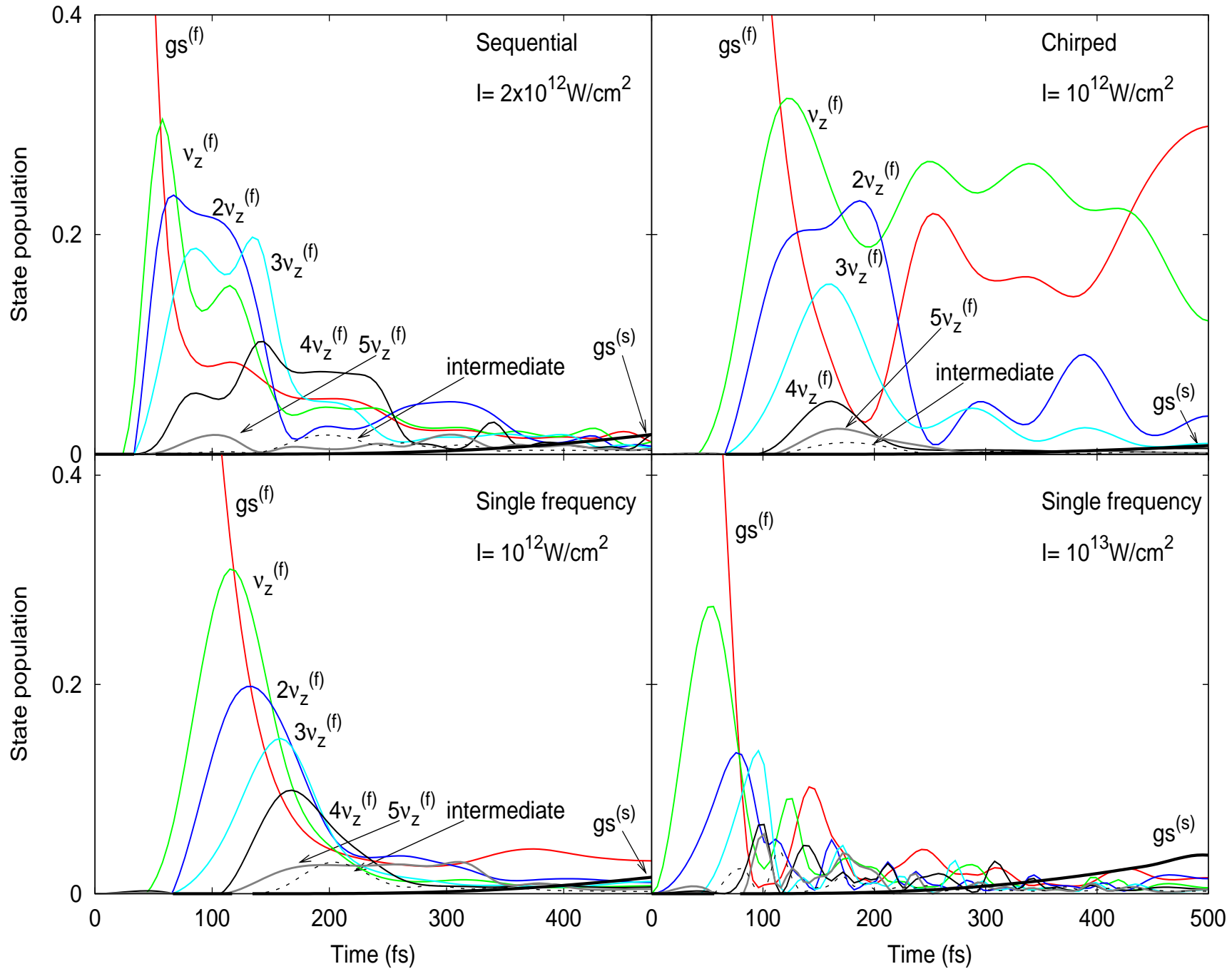
Proposed excitation mechanism



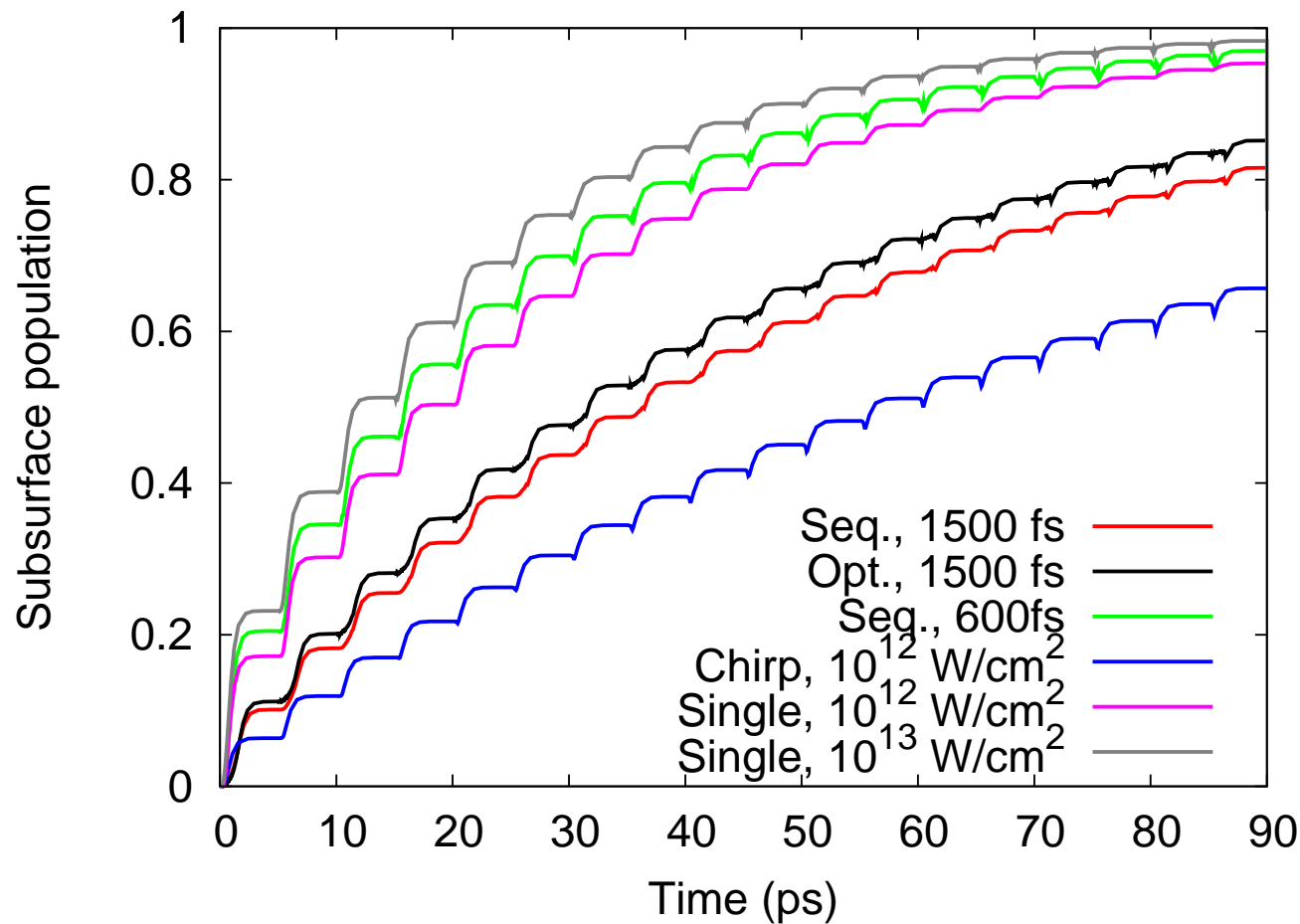
Excitation using long pulses



Excitation using short rational pulses



Selective Subsurface Absorption by Laser Distillation (SSALaD)



Transfer efficiency

$$P(t) = P_0 (1 - e^{-Rt})$$

Simulation	P_0 (%)	R (ps ⁻¹)
Sequential, 1500 fs	98.1	0.0197
Optimized, 1500 fs	98.1	0.0222
Sequential, 600 fs	99.1	0.0412
Chirped, 10^{12} W/cm ²	96.7	0.0126
Single, 10^{12} W/cm ²	99.3	0.0353
Single, 10^{13} W/cm ²	99.2	0.0482

Conclusion and outlook

- **State-resolved anharmonic transition rate model**
 - Position dependence relies on definition of good embedding density
 - Anharmonicity included via multi-D integration of vibrational WF
 - Scaling can be related to existing *ab initio* models
- **Application to state-resolved dynamics**
 - Laser-induced selective subsurface absorption of H in Pd(111)
 - Influence on the short-term population dynamics
 - Laser distillation achieves complete target population, but with different rates
- **Future work**
 - Perform optimal control simulations to maximize transfer rate
 - Study STM-induced bulk-to-subsurface transition
 - Investigate possibility of isotope separation

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- Dr. Serge Monturet for periodic density calculations
- The group of Prof. Peter Saalfrank in Potsdam

Thank you for your attention!!!